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Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.32 \text{ V}$ at $I_F = 5.0 \text{ A}$



PRIMARY CHARACTERISTICS			
I _{F(AV)}	2 x 20 A		
V_{RRM}	60 V		
I _{FSM}	240 A		
V _F at I _F = 20 A	0.48 V		
T_J max.	150 °C		
Package	ITO-220AB		
Circuit configuration	Common cathode		

FEATURES





- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106 RoHS
- Material categorization: for definitions

compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VFT4060C	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	60	V	
Maximum average forward rectified current per device	I _{F(AV)}	40		
(fig. 1) per diode		20	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	240	А	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Isolation voltage from terminal to heatsink t = 1 min	V _{AC}	1500	V	
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150	°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.43	-	. V
	I _F = 10 A			0.48	-	
	I _F = 20 A			0.53	0.62	
	I _F = 5.0 A	T _A = 125 °C		0.32	-	
	I _F = 10 A			0.39	-	
	I _F = 20 A			0.48	0.57	
Reverse current per diode	V - 60 V	T _A = 25 °C	I _R ⁽²⁾	-	6.0	- mA
	V _R = 60 V	T _A = 125 °C		34	190	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT4060C	UNIT
Typical thermal resistance	per diode	$R_{ heta JC}$	5.0	°C/W
	per device		3.0	C/VV

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	VFT4060C-E3/4W	1.75	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

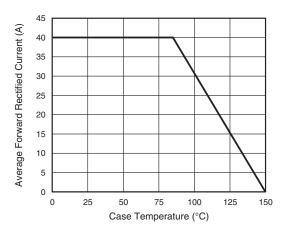


Fig. 1 - Maximum Forward Current Derating Curve

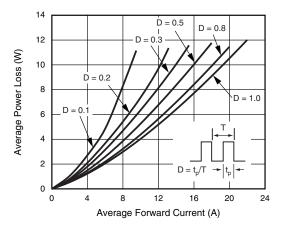


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

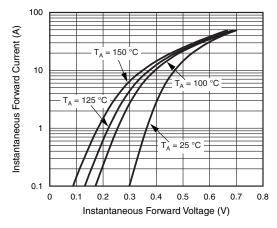


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

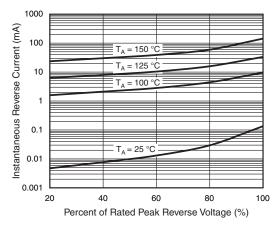
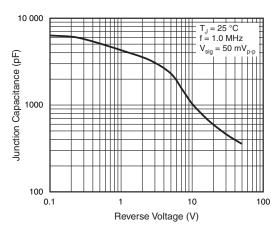


Fig. 4 - Typical Reverse Characteristics Per Diode



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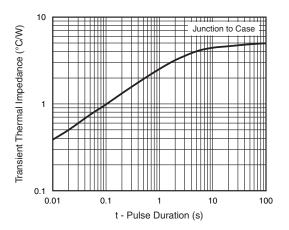
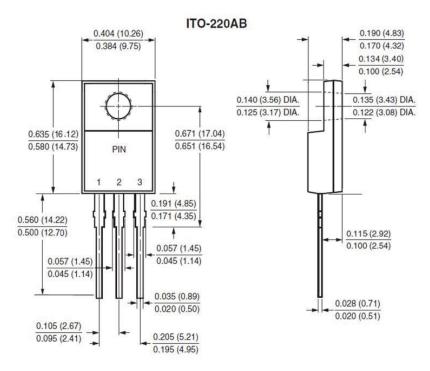


Fig. 6 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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